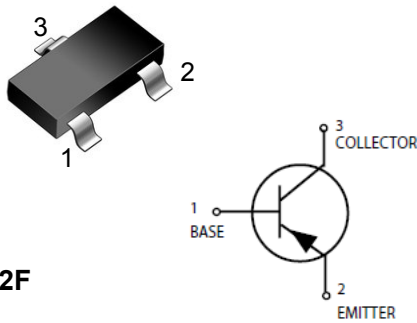


SOT-23



MARKING: 2F

Features

As complementary type the NPN transistor PMBT2222A is recommended
Epitaxial planar die construction
Halogen free and RoHS compliant

Mechanical Data

SOT-23 Small Outline Plastic Package
Epoxy UL: 94V-0

Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard
SOT-23	Tape/Reel, 7" reel	3000	EIA-481-1

Maximum Ratings & Thermal Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-60	V
V_{CEO}	Collector-Emitter Voltage	-60	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current -Continuous	-600	mA
P_C	Total Device Dissipation	250	mW
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	500	°C/W
T_J	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-55 to +150	°C

Electrical Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

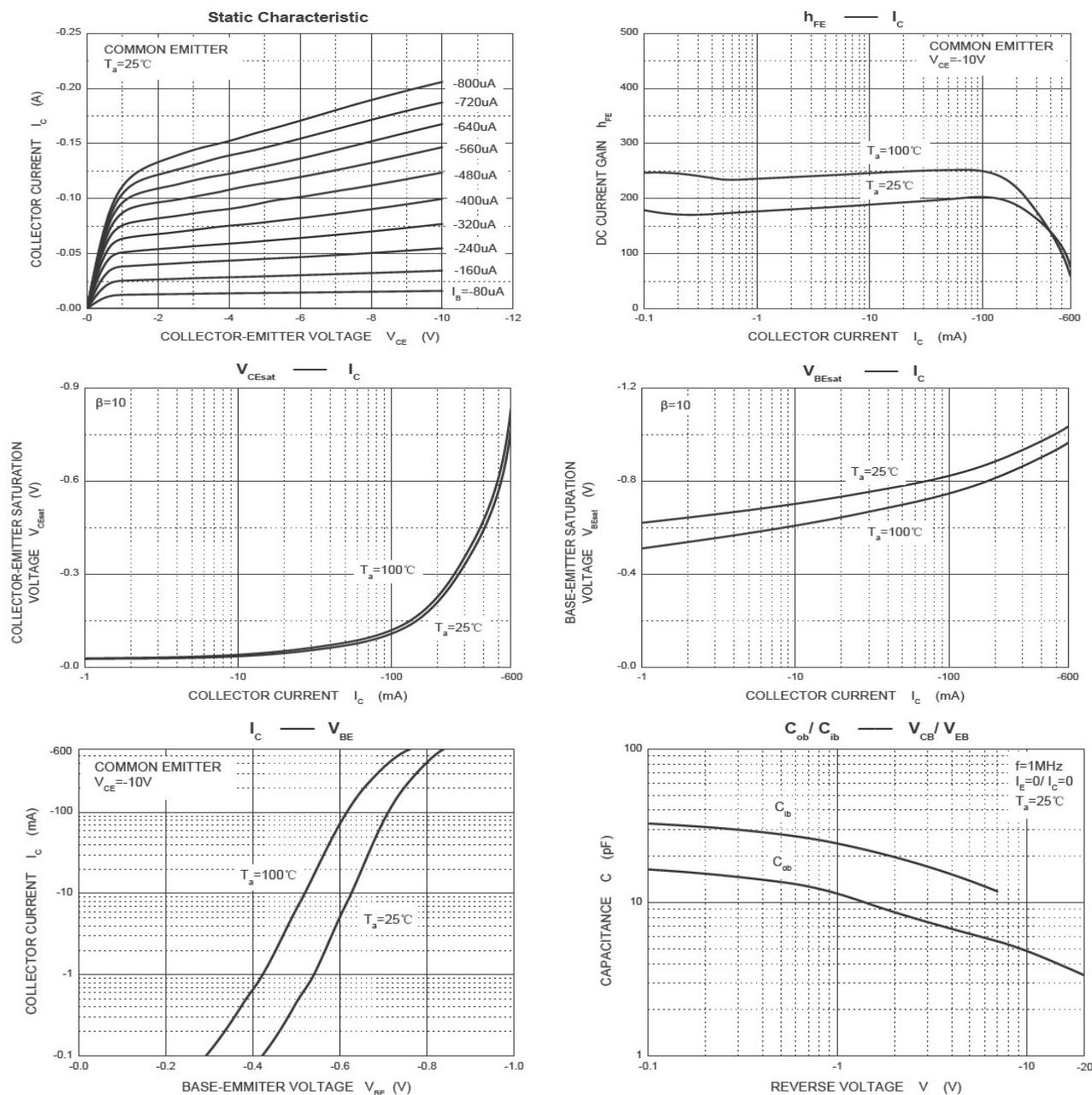
Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -10\mu A, I_E = 0$	-60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}^*$	$I_C = -10mA, I_B = 0$	-60			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -10\mu A, I_C = 0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB} = -50V, I_E = 0$			-20	nA
Base cut-off current	I_{EBO}	$V_{CE} = -3V, I_C = 0$			-10	nA
Collector cut-off current	I_{CEX}	$V_{CE} = -30V, V_{BE(off)} = -0.5V$			-50	nA
DC current gain	$h_{FE(1)}$	$V_{CE} = -10V, I_C = -150mA$	100		300	
	$h_{FE(2)}$	$V_{CE} = -10V, I_C = -0.1mA$	75			
	$h_{FE(3)}$	$V_{CE} = -10V, I_C = -1mA$	100			
	$h_{FE(4)}$	$V_{CE} = -10V, I_C = -10mA$	100			
	$h_{FE(5)}$	$V_{CE} = -10V, I_C = -500mA$	50			
Collector-emitter saturation voltage	$V_{CE(sat)}^*$	$I_C = -150mA, I_B = -15mA$			-0.4	V
	$V_{CE(sat)}^*$	$I_C = -500mA, I_B = -50mA$			-1.6	V
Base-emitter saturation voltage	$V_{BE(sat)}^*$	$I_C = -150mA, I_B = -15mA$			-1.3	V
	$V_{BE(sat)}^*$	$I_C = -500mA, I_B = -50mA$			-2.6	V
Transition frequency	f_T	$V_{CE} = -20V, I_C = -50mA, f = 100MHz$	200			MHz
Delay time	t_d	$V_{CE} = -30V, I_C = -150mA, I_{B1} = -15mA$			10	nS
Rise time	t_r				25	nS
Storage time	t_s	$V_{CE} = -6V, I_C = -150mA,$			225	nS
Fall time	t_f	$I_{B1} = -I_{B2} = -15mA$			60	nS

*Pulse test: $t_p \leq 300\mu S, \delta \leq 0.02$.

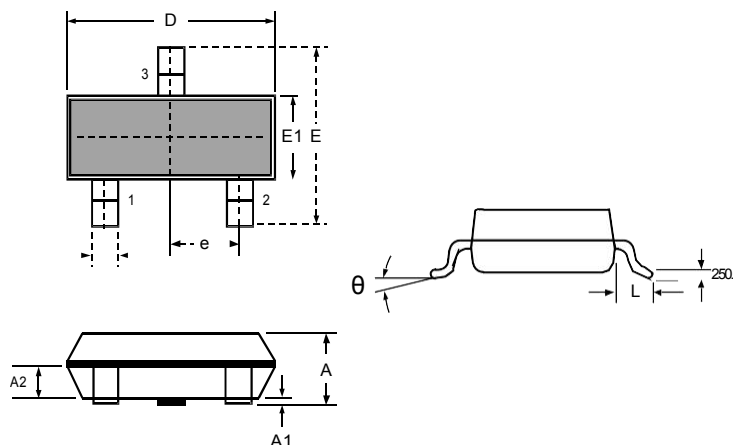
CLASSIFICATION OF $h_{FE}(1)$

HFE	100-300	
RANK	L	H
RANGE	100-200	200-300

Ratings and Characteristic Curves



Package Outline Dimensions: SOT-23



DIMENSIONS

SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
D	2.800	3.000	0.110	0.118
b	0.300	0.500	0.012	0.020
E	2.250	2.550	0.089	0.100
E1	1.200	1.400	0.047	0.055
e	0.950 BSC		0.037 BSC	
L	0.300	0.500	0.012	0.020
θ	0	8°	0	8°

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